PROPERTIES OF SUPERCONDUCTORS

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The following tables include superconductive properties of selected elements, compounds, and alloys. Individual tables are given for thin films, elements at high pressures, superconductors with high critical magnetic fields, and high critical temperature superconductors.

The historically first observed and most distinctive property of a superconductive body is the near total loss of resistance at a critical temperature (T_c) that is characteristic of each material. Figure 1(a) below illustrates schematically two types of possible transitions The sharp vertical discontinuity in resistance is indicative of that found for a single crystal of a very pure element or one of a few well annealed alloy compositions. The broad transition, illustrated by broken lines, suggests the transition shape seen for materials that are not homogeneous and contain unusual strain distributions. Careful testing of the resistivity limit for superconductors shows that it is less than 4×10^{-23} ohm cm, while the lowest resistivity observed in metals is of the order of 10^{-13} ohm cm. If one compares the resistivity of a superconductive body to that of copper at room temperature, the superconductive body is at least 10^{17} times less resistive.

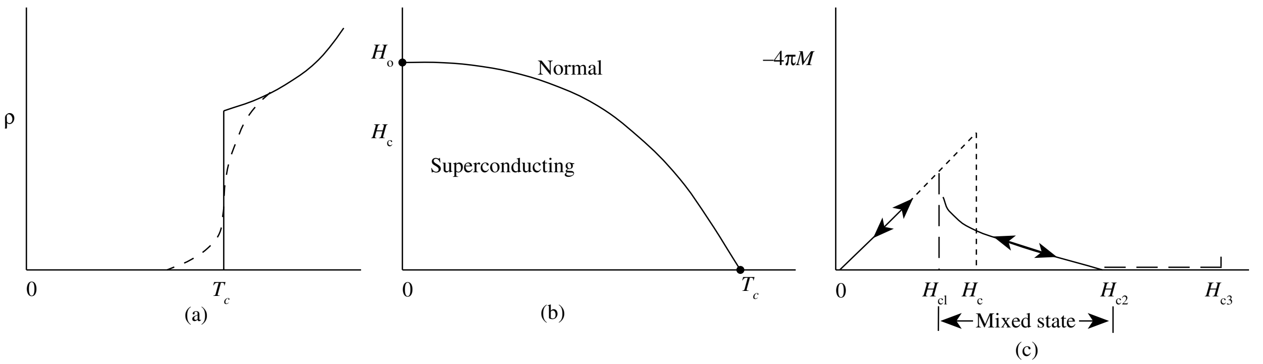

FIGURE 1. **P**hysical properties of superconductors. (a) Resistivity vs. temperature for a pure and perfect lattice (solid line); impure and/or imperfect lattice (broken line). (b) Magnetic-field temperature dependence for Type-I or "soft" superconductors. (c) Schematic magnetization curve for "hard" or Type-II superconductors**.**

The temperature interval ΔT_c, over which the transition between the normal and superconductive states takes place, may be of the order of as little as 2×10^{-5} K or several K in width, depending on the material state. The narrow transition width was attained in 99.9999% pure gallium single crystals.

A Type-I superconductor below T_c, as exemplified by a pure metal, exhibits perfect diamagnetism and excludes a magnetic field up to some critical field H_c, whereupon it reverts to the normal state as shown in the H-T diagram of Figure 1(b).

The magnetization of a typical high-field superconductor is shown in Figure 1(c). The discovery of the large current-carrying capability of Nb_3Sn and other similar alloys has led to an extensive study of the physical properties of these alloys. In brief, a high-field superconductor, or Type-II superconductor, passes from the perfect diamagnetic state at low magnetic fields to a mixed state and finally to a sheathed state before attaining the normal resistive state of the metal. The magnetic field values separating the four stages are given as H_{c1}, H_{c2}, and H_{c3}. The superconductive state below H_{c1} is perfectly diamagnetic, identical to the state of most pure metals of the "soft" or Type-I superconductor. Between H_{c1} and H_{c2} a "mixed superconductive state" is found in which fluxons (a minimal unit of magnetic flux) create lines of normal flux in a superconductive matrix. The volume of the normal state is proportional to $-4\pi M$ in the "mixed state" region. Thus at H_{c2} the fluxon density has become so great as to drive the interior volume of the superconductive body completely normal. Between H_{c2} and H_{c3} the superconductor has a sheath of current-carrying superconductive material at the body surface, and above H_{c3} the normal state exists. With several types of careful measurement, it is possible to determine H_{c1}, H_{c2}, and H_{c3}. Table 6 contains some of the available data on high-field superconductive materials.

High-field superconductive phenomena are also related to specimen dimension and configuration. For example, the Type-I superconductor, Hg, has entirely different magnetization behavior in high magnetic fields when contained in the very fine sets of filamentary tunnels found in an unprocessed Vycor glass. The great majority of superconductive materials are Type-II. The elements in very pure form and a very few precisely stoichiometric and well annealed compounds are Type I with the possible exceptions of vanadium and niobium.

Metallurgical Aspects. The sensitivity of superconductive properties to the material state is most pronounced and has been used in a reverse sense to study and specify the detailed state of alloys. The mechanical state, the homogeneity, and the presence of impurity atoms and other electron-scattering centers are all capable of controlling the critical temperature and the current-carrying capabilities in high-magnetic fields. Well annealed specimens tend to show sharper transitions than those that are strained or inhomogeneous. This sensitivity to mechanical state underlines a general problem in the tabulation of properties for superconductive materials. The occasional divergent values of the critical temperature and of the critical fields quoted for a Type-II superconductor may lie in the variation in sample preparation. Critical temperatures of materials studied early in the history of superconductivity must be evaluated in light of the probable metallurgical state of the material, as well as the availability of less pure starting elements. It has been noted that recent work has given extended consideration to the metallurgical aspects of sample preparation.

Symbols in tables: T_c: Critical temperature; H_o: Critical magnetic field in the $T = 0$ limit; θ_D: Debye temperature; and γ: Electronic specific heat.

TABLE 1. Selective Properties of Superconductive Elements

Element	T_c(K)	H_o(oersted)	θ_D(K)	γ(mJ mol^{-1}K^{-1})
Al	1.175 ± 0.002	104.9 ± 0.3	420	1.35
Am* (α,?)	0.6			
Am* (β,?)	1.0			
Be	0.026			0.21
Cd	0.517 ± 0.002	28 ± 1	209	0.69
Ga	1.083 ± 0.001	58.3 ± 0.2	325	0.60
Ga (β)	5.9, 6.2	560		
Ga (γ)	7	950, HF[a]		
Ga (Δ)	7.85	815, HF		
Hf	0.128	12.7		2.21
Hg (α)	4.154 ± 0.001	411 ± 2	87, 71.9	1.81
Hg (β)	3.949	339	93	1.37
In	3.408 ± 0.001	281.5 ± 2	109	1.672
Ir	0.1125 ± 0.001	16 ± 0.05	425	3.19
La (α)	4.88 ± 0.02	800 ± 10	151	9.8
La (β)	6.00 ± 0.1	1096, 1600	139	11.3
Lu	0.1 ± 0.03	350 ± 50		
Mo	0.915 ± 0.005	96 ± 3	460	1.83
Nb	9.25 ± 0.02	2060 ± 50, HF	276	7.80
Os	0.66 ± 0.03	70	500	2.35
Pa	1.4			
Pb	7.196 ± 0.006	803 ± 1	96	3.1
Re	1.697 ± 0.006	200 ± 5	4.5	2.35
Ru	0.49 ± 0.015	69 ± 2	580	2.8
Sn	3.722 ± 0.001	305 ± 2	195	1.78
Ta	4.47 ± 0.04	829 ± 6	258	6.15
Tc	7.8 ± 0.1	1410, HF	411	6.28
Th	1.38 ± 0.02	1.60 ± 3	165	4.32
Ti	0.40 ± 0.04	56	415	3.3
Tl	2.38 ± 0.02	178 ± 2	78.5	1.47
U	0.2			
V	5.40 ± 0.05	1408	383	9.82
W	0.0154 ± 0.0005	1.15 ± 0.03	383	0.90
Zn	0.85 ± 0.01	54 ± 0.3	310	0.66
Zr	0.61 ± 0.15	47	290	2.77
Zr (ω)	0.65, 0.95			

TABLE 2. Range of Critical Temperatures Observed for Superconductive Elements in Thin Films Condensed Usually at Low Temperatures

Element	T_c Range (K)	Comments	Element	T_c Range (K)	Comments
Al	1.15–5.7	HF[a]	Nb	2.0–10.1	
Be	5–9.75	HF	Pb	1.8–7.5	
Bi	6.17–6.6		Re	1.7–7	
Cd			Sn	3.5–6	
(Disordered)	0.79–0.91		Ta	<1.7–4.51	HF[a]
(Ordered)	0.53–0.59		Tc	4.6–7.7	
Ga	2.5–8.5	HF	Ti	1.3 Max	
Hg	3.87–4.5		Tl	2.33–2.96	
In	2.2–5.6	HF	V	1.8–6.02	
La	3.55–6.74		W	<1.0–4.1	
Mo	3.3–8.0		Zn	0.77–1.9	

[a] HF denotes high magnetic field superconductive properties.

TABLE 3. Elements Exhibiting Superconductivity Under or After Application of High Pressure

Element	T_c Range (K)	Pressure (kbar)	Element	T_c Range (K)	Pressure (kbar)
Al	1.98–0.075	0–62	Pb II	3.55	160
As	0.31–0.5	220–140	Re II	2.3 Max.	"Plastic" compression
	0.2–0.25	140–100			
Ba II	1–1.8	55–85	Sb (prepared 120 kbar, held below 77K)	2.6–2.7	
III	1.8–5	85–144			
IV	4.5–5.4	144–190			
Bi II	3.9	25–27	Sb II	3.55–3.40	85–150
III	6.55–7.25	28–38	Se II	6.75, 6.95	130
IV	7.0, 8.7–6.0	43, 43–62	Si	6.7–7.1	120–130
V	6.7, 8.3	48–80	Sn II	5.2–4.85	125–160
VI	8.55	90, 92–101	III	5.30	113
VII(?)	8.2	30	Te II	2.4–5.1	38–55
Ce (α)	0.020–0.045	20–35		4.1–4.2	53–62
Ce (α′)	1.9–1.3	45–125	IV	4.72–4	63–80
Cs V	1.5	>125	( )	3.3–2.8	100–260
Ga II	6.38	≥35	Tl (cubic form)	1.45	35
II′	7.5	≥35 then P removed	(hexagonal form)	1.95	35
Ge	5.35	115	U	2.4–0.4	10–85
Lu	0.022–1.0	45–190	Y	1.7–2.5	110–160
P	5.8	170	Zr (omega form, metastable)	1–1.7	60–130

TABLE 4. Superconductive Compounds and Alloys

All compositions are denoted on an atomic basis, i.e., AB, AB_2, or AB_3 for compounds, unless noted. Solid solutions or odd compositions may be denoted as A_zB_{1-z} or A_zB. A series of three or more alloys is indicated as A_xB_{1-x} or by actual indication of the atomic fraction range, such as $A_{0-0.6}B_{1-0.4}$. The critical temperature of such a series of alloys is denoted by a range of values or possibly the maximum value.

The selection of the critical temperature from a transition in the effective permeability, or the change in resistance, or possibly the incremental changes in frequency observed by certain techniques is not often obvious from the literature. Most authors choose the mid-point of such curves as the probable critical temperature of the idealized material, while others will choose the highest temperature at which a deviation from the normal state property is observed. In view of the previous discussion concerning the variability of the superconductive properties as a function of purity and other metallurgical aspects, it is recommended that appropriate literature be checked to determine the most probable critical temperature or critical field of a given alloy.

A very limited amount of data on critical fields, H_o, is available for these compounds and alloys; these values are given at the end of the table.

A. Superconductors with T_c < 10 K

Substance	T_c, K	Crystal structure type
$Ag_{3.3}Al$	0.34	A12-cI58 (Mn)
$Ag_xAl_yZn_{1-x-y}$	0.15	Cubic
$AgBi_2$	2.87–3.0	
$Ag_7F_{0.25}N_{0.75}O_{10.25}$	0.85–0.90	
Ag_2F	0.0.066	
Ag_7FO_8	0.3	Cubic
$Ag_{0.8-0.3}Ga_{0.2-0.7}$	6.5–8	
Ag_4Ge	0.85	Hex., c.p.
$Ag_{0.438}Hg_{0.562}$	0.64	$D8_2$
$AgIn_2$	~2.4	C16
$Ag_{0.1}In_{0.9}Te$ (n = 1.4 × 10^{22})*	1.2–1.89	B1
$Ag_{0.2}In_{0.8}Te$ (n = 1.07 × 10^{22})	0.77–1.00	B1
AgLa	0.94	B2-cP2 (CsCl)
AgLa (9.5 kbar)	1.2	B2
AgLu	0.33	B2-cP2
$AgMo_4S_5$	9.1	hR15 (Mo_6PbS_8)
$Ag_{1.2}Mo_6Se_8$	5.9	Same
Ag_7NO_{11}	1.04	Cubic
Ag_xPb_{1-x}	7.2 max.	
Ag_4Sn	0.1	h**
Ag_xSn_{1-x}	1.5–3.7	
Ag_xSn_{1-x} (film)	2.0–3.8	
$AgTe_3$	2.6	Cubic
AgTh	2.2	C16-tI12 (Al_2Cu)
$AgTh_2$	2.26	C16
$Ag_{0.03}Tl_{0.97}$	2.67	
$Ag_{0.94}Tl_{0.06}$	2.32	
AgY	0.33	B2-cP2 (CsCl)
Ag_xZn_{1-x}	0.5–0.845	
$AlAu_4$	0.4–0.7	Like A13
Al_2Au	0.1	C1-cF12 (CaF_2)
Al_2CMo_3	9.8–10.2	A13+trace 2nd. phase
Al_2CaSi	5.8	
$Al_{0.131}Cr_{0.088}V_{0.781}$	1.46	Cubic
$AlGe_2$	1.75	

Substance	T_c, K	Crystal structure type
Al_2Ge_2U	1.6	LI_2-cP4 (Cu_3Au)
$AlLa_3$	5.57	DO_{19}
Al_2La	3.23	C15
Al_2Lu	1.02	C15-cF24 (Cu_2Mg)
Al_3Mg_2	0.84	F.C.C.
$AlMo_3$	0.58	A15
$AlMo_6Pd$	2.1	
AlN	1.55	B4
Al_2NNb_3	1.3	A13
Al_3Nb	0.64	tI8 (Al_3Ti)
AlOs	0.39	B2
Al_3Os	5.90	
AlPb (film)	1.2–7	
Al_2Pt	0.48–0.55	C1
Al_5Re_{24}	3.35	A12
AlSb	2.8	B4-tI4 (Sn)
Al_2Sc	1.02	C15-cF24 (Cu_2Mg)
Al_2Si_2U	1.34	LI_2-cP4 (Cu_3Au)
$AlTh_2$	0.1	C16-tI12 (Al_2Cu)
Al_3Th	0.75	DO_{19}
$Al_xTi_yV_{1-x-y}$	2.05–3.62	Cubic
$Al_{0.108}V_{0.892}$	1.82	Cubic
Al_2Y	0.35	C15-cF24 (Cu_2Mg)
Al_3Yb	0.94	LI_2-cP4 (Cu_3Au)
Al_xZn_{1-x}	0.5–0.845	
$AlZr_3$	0.73	LI_2
AsBiPb	9.0	
AsBiPbSb	9.0	
AsHfOs	3.2	C22-hP9 (Fe_2P)
AsHfRu	4.9	same
$As_{0.33}InTe_{0.67}$ ($n = 1.24 \times 10^{22}$)	0.85–1.15	B1
$As_{0.5}InTe_{0.5}$ ($n = 0.97 \times 10^{22}$)	0.44–0.62	B1
As_4La_3	0.6	cI28 (Th_3P_4)
$AsNb_3$	0.3	$L1_2$-tP32
$As_{0.50}Ni_{0.06}Pd_{0.44}$	1.39	C2
$AsNi_{0.25}Pd_{0.75}$	1.6	$B8_1$-hP4 (NiAs)
AsOsZr	8.0	C22-hP9 (Fe_2P)
AsPb	8.4	
$AsPd_2$ (low-temp. phase)	0.60	Hexagonal
$AsPd_2$ (high-temp. phase)	1.70	C22
$AsPd_5$	0.46	Complex
As_3Pd_5	1.9	
AsRh	0.58	B31
$AsRh_{1.4-1.6}$	< 0.03–0.56	Hexagonal
AsSn	4.10	
AsSn ($n = 2.14 \times 10^{22}$)	3.41–3.65	B1
$As_{\sim2}Sn_{\sim3}$	3.5–3.6; 1.21–1.17	
As_3Sn_4 ($n = 0.56 \times 10^{22}$)	1.16–1.19	Rhombohedral
AsV_3	0.20	A15-cP8 (Cr_3Si)
Au_5Ba	0.4–0.7	$D2_d$
AuBe	2.64	B20
Au_2Bi	1.80	C15
Au_5Ca	0.34–0.38	$C15_b$
$AuGa_2$	1.6	C1-cF12 (CaF_2)
AuGa	1.2	B31
$Au_{0.40-0.92}Ge_{0.60-0.08}$	<0.32–1.63	Complex
$AuIn_2$	0.2	C1-cF12
AuIn	0.4–0.6	Complex
AuLu	<0.35	B2
$AuNb_3$	1.2	A2
$AuPb_2$	3.15	
$AuPb_2$ (film)	4.3	
$AuPb_3$	4.40	
$AuPb_3$ (film)	4.25	
Au_2Pb	1.18; 6–7	C15
$AuSb_2$	0.58	C2
AuSn	1.25	$B8_1$
Au_xSn_{1-x} (film)	2.0–3.8	
Au_5Sn	0.7–1.1	A3
$AuTa_{4.3}$	0.55	A15-cP8 (Cr_3Si)
Au_3Te_5	1.62	Cubic
$AuTh_2$	3.08	C16
AuTl	1.92	
AuV_3	0.74	A15
Au_xZn_{1-x}	0.50–0.845	
$AuZn_3$	1.21	Cubic
Au_xZr_y	1.7–2.8	A3
$AuZr_3$	0.92	A15
$B_2Ba_{0.67}Pt_3$	5.60	hP12 (B_2BaPt_3)
$BCMo_2$	5.4	Orthorhombic
$BCMo_2$	5.3–7.0	Same
$B_2Ca_{0.67}Pt_3$	1.57	hP12
B_4ErIr_4	2.1	tP18 (B_4CeCo_4)
B_4ErRh_4	4.3	oC108 (B_4LuRh_4)
B_4ErRh_4	8.7	tP18 (B_4CeCo_4)
BHf	3.1	Cubic
B_4HoIr_4	2.0	tP18
B_4HoRh_4	1.4	oC108
B_2Ir_3La	1.65	hP6 ($CaCu_5$)
B_2Ir_3Th	2.09	Same
B_4Ir_4Tm	1.6	tP18
B_6La	5.7	
B_2LaRh_3	2.82	hP6
$B_{12}Lu$	0.48	
B_2LuOs	2.66	oP16 (B_2LuRu)
B_2LuOs_3	4.62	hP6
B_4LuRh_4	6.2	oC108
B_2LuRu	9.86	oP16
B_4LuRu_4	2.0	tI72 (B_4LuRu_4)
BMo	0.5 (extrapol.)	
BMo_2	4.74	C16
BNb	8.25	B_f
B_4NdRh_4	5.3	tP18
B_2OsSc	1.34	oP16
B_2OsY	2.22	oP16
$B_2Pt_3Sr_{0.67}$	2.78	hP12 (B_2BaPt_3)
BRe_2	2.80; 4.6	
$B_4Rh_{3.4}Ru_{0.6}$	8.38	tI72
B_4Rh_4Sm	2.7	tP18
B_4Rh_4Th	4.3	Same
B_4Rh_4Tm	9.8	Same
B_4Rh_4Tm	5.4	oC108
$B_{0.3}Ru_{0.7}$	2.58	$D10_2$
B_4Ru_4Sc	7.2	tI72
B_2Ru_3Th	1.79	hP6
B_2Ru_3Y	2.85	Same
B_2Ru Y	7.80	oP16
B_4Ru_4Y	1.4	tI72
$B_{12}Sc$	0.39	
BTa	4.0	B_f

Substance	T_c, K	Crystal structure type
BTa_2	3.12	C16-tI12 (Al_2Cu)
B_6Th	0.74	
BW_2	3.1	C16
B_6Y	6.5–7.1	
$B_{12}Y$	4.7	
BZr	3.4	Cubic
$B_{12}Zr$	5.82	
$BaBi_3$	5.69	Tetragonal
$Ba_2Mo_{15}Se_{19}$	2.75	hP15 (Mo_6PbS_8)
$Ba_xO_3Sr_{1-x}Ti$ ($n = 4.2 \times 10^{19}$)	<0.1–0.55	
$Ba_{0.13}O_3W$	1.9	Tetragonal
$Ba_{0.14}O_3W$	<1.25–2.2	Hexagonal
$BaRh_2$	6.0	C15
$Be_{22}Mo$	2.51	Cubic ($Be_{22}Re$)
$Be_8Nb_5Zr_2$	5.2	
$Be_{0.98-0.92}Re_{0.02-0.08}$ (quenched)	9.5–9.75	Cubic
$Be_{0.957}Re_{0.043}$	9.62	Cubic ($Be_{22}Re$)
BeTc	5.21	Cubic
$Be_{22}W$	4.12	Cubic ($Be_{22}Re$)
$Be_{13}W$	4.1	Tetragonal
Bi_3Ca	2.0	
$Bi_{0.5}Cd_{0.13}Pb_{0.25}Sn_{0.12}$ (weight fractions)	8.2	
BiCo	0.42–0.49	
Bi_2Cs	4.75	C15
Bi_xCu_{1-x} (electrodeposited)	2.2	
BiCu	1.33–1.40	
Bi_3Fe	1.0	m**
$Bi_{0.019}In_{0.981}$	3.86	
$Bi_{0.05}In_{0.95}$	4.65	α-phase
$Bi_{0.10}In_{0.90}$	5.05	Same
$Bi_{0.15-0.30}In_{0.85-0.70}$	5.3–5.4	α- and β-phases
$Bi_{0.34-0.48}In_{0.66-0.52}$	4.0–4.1	
Bi_3In_5	4.1	
$BiIn_2$	5.65	β-phase
Bi_2Ir	1.7–2.3	
Bi_2Ir (quenched)	3.0–3.96	
BiK	3.6	
Bi_2K	3.58	C15
BiLi	2.47	$L1_o$, α-phase
$Bi_{4-9}Mg$	0.7–~1.0	
Bi_3Mo	3–3.7	
BiNa	2.25	$L1_o$
$BiNb_3$	4.5	A15-cP8 (Cr_3Si)
$BiNb_3$ (high pressure and temperature)	3.05	A15
BiNi	4.25	$B8_1$
Bi_3Ni	4.06	Orthorhombic
$BiNi_{0.5}Rh_{0.5}$	3.0	$B8_1$-hP4 (AsNi)
$Bi_{0.5}NiSb_{0.5}$	2.0	Same
$Bi_{1-0}Pb_{0-1}$	7.26–9.14	
$Bi_{1-0}Pb_{0-1}$ (film)	7.25–8.67	
$Bi_{0.05-0.40}Pb_{0.95-0.60}$	7.35–8.4	H.C.P. to ε-phase
Bi_2Pb	4.25	t**
BiPbSb	8.9	
$Bi_{0.5}Pb_{0.31}Sn_{0.19}$ (weight fractions)	8.5	
$Bi_{0.5}Pb_{0.25}Sn_{0.25}$	8.5	
$BiPd_2$	4.0	
$Bi_{0.4}Pd_{0.6}$	3.7–4	Hexagonal, ordered
BiPd	3.7	Orthorhombic
Bi_2Pd	1.70	Monoclinic, α-phase
Bi_2Pd	4.25	Tetragonal, β-phase
$BiPd_{0.45}Pt_{0.55}$	3.7	$B8_1$-hP4 (NiAs)
BiPdSe	1.0	C2
BiPdTe	1.2	C2
BiPt	1.21	$B8_1$
$Bi_{0.1}PtSb_{0.9}$	2.05; 1.5	$B8_1$-hP4 (NiAs)
BiPtSe	1.45	C2
BiPtTe	1.15	C2
Bi_2Pt	0.155	Hexagonal
Bi_2Rb	4.25	C15
$BiRe_2$	1.9–2.2	
BiRh	2.06	$B8_1$
Bi_3Rh	3.2	Orthorhombic (NiB_3)
Bi_4Rh	2.7	Hexagonal
BiRu	5.7	m**
Bi_3Sn	3.6–3.8	
BiSn	3.8	
Bi_xSn_y	3.85–4.18	
Bi_3Sr	5.62	$L1_2$
Bi_3Te	0.75–1.0	
Bi_5Tl_3	6.4	
$Bi_{0.26}Tl_{0.74}$	4.4	Cubic, disordered
$Bi_{0.26}Tl_{0.74}$	4.15	$L1_2$, ordered (?)
Bi_2Y_3	2.25	
Bi_3Zn	0.8–0.9	
$Bi_{0.3}Zr_{0.7}$	1.51	
$BiZr_3$	2.4–2.8	
$BrMo_6Se_7$	7.1	hP15 (Mo_6PbS_8)
$Br_3Mo_6Se_5$	7.1	Same
CCs_x	0.020–0.135	Hexagonal
CFe_3	1.30	DO_{11}-oP16 (Fe_3C)
$CGaMo_2$	3.7–4.1	Hexagonal
$CHf_{0.5}Mo_{0.5}$	3.4	B1
$CHf_{0.3}Mo_{0.7}$	5.5	B1
$CHf_{0.25}Mo_{0.75}$	6.6	B1
$CHf_{0.7}Nb_{0.3}$	6.1	B1
$CHf_{0.6}Nb_{0.4}$	4.5	B1
$CHf_{0.5}Nb_{0.5}$	4.8	B1
$CHf_{0.4}Nb_{0.6}$	5.6	B1
$CHf_{0.25}Nb_{0.75}$	7.0	B1
$CHf_{0.2}Nb_{0.8}$	7.8	B1
$CHf_{0.9-0.1}Ta_{0.1-0.9}$	5.0–9.0	B1
CK (excess K)	0.55	Hexagonal
C_8K	0.39	Hexagonal
C_2La	1.66	tI6 (CaC_2)
C_2Lu	3.33	Same
$C_{0.40-0.44}Mo_{0.60-0.56}$	9–13	
C_3MoRe	3.8	B1-cF8
$C_{0.6}Mo_{4.8}Si_3$	7.6	$D8_8$
$CMo_{0.2}Ta_{0.8}$	7.5	B1
$CMo_{0.5}Ta_{0.5}$	7.7	B1
$CMo_{0.75}Ta_{0.25}$	8.5	B1
$CMo_{0.8}Ta_{0.2}$	8.7	B1
$CMo_{0.85}Ta_{0.15}$	8.9	B1
CMo_xV_{1-x}	2.9–9.3	B1
CMo_xZr_{1-x}	9.8	B1
$C_{0.984}Nb$	9.8	B1
CNb_2	9.1	
CNb_xTi_{1-x}	<4.2–8.8	B1
$CNb_{0.1-0.9}Zr_{0.9-0.1}$	4.2–8.4	B1

Substance	T_c, K	Crystal structure type
CRb_x (Au)	0.023–0.151	Hexagonal
$CRe_{0.06}W$	5.0	
CRu	2.00	hP2 (CW)
$C_{0.98}7Ta$	9.7	
$C_{0.848–0.987}$	2.04–9.7	
CTa (film)	5.09	B1
CTa_2	3.26	L'_3
$CTa_{0.4}Ti_{0.6}$	4.8	B1
$Cta_{1–0.4}W_{0–0.6}$	8.5–10.5	B1
$CTa_{0.2–0.9}Zr_{0.8–0.1}$	4.6–8.3	B1
CTc (excess C)	3.85	Cubic
$CTi_{0.5–0.7}W_{0.5–0.3}$	6.7–2.1	B1
CW	1.0	
CW_2	2.74	L'_3
CW_2	5.2	F.C.C.
C_2Y	3.88	tI6 (CaC_2)
$Ca_3Co_4Sn_{13}$	5.9	cP40 ($Pr_3Rh_2Sn_{13}$)
$Ca_3Ge_{13}Rh_4$	2.1	Same
CaHg	1.6	B2-cP2 (CsCl)
$CaHg_3$	1.6	hP8 (Ni_3Sn)
$CaIr_2$	6.15	C15
$Ca_3Ir_4Sn_{13}$	7.1	cP40
$Ca_xO_3Sr_{1-x}Ti$ (n = 3.7–11 × 10^{19})	< 0.1–0.55	
$Ca_{0.1}O_3W$	1.4–3.4	Hexagonal
CaPb	7.0	
$CaRh_2$	6.40	C15
$CaRh_{1.2}Sn_{4.5}$	8.7	cP40
$CaTl_3$	2.0	B2-cP2
$Cd_{0.3–0.5}Hg_{0.7–0.5}$	1.70–1.92	
CdHg	1.77; 2.15	Tetragonal
$Cd_{0.0075–0.05}In_{0.9925–0.95}$	3.24–3.36	Tetragonal
$Cd_{0.97}Pb_{0.03}$	4.2	
CdSn	3.65	
$Cd_{0.17}Tl_{0.83}$	2.3	
$Cd_{0.18}Tl_{0.82}$	2.54	
$CeCo_2$	0.84	C15
$CeCo_{1.67}Ni_{0.33}$	0.46	C15
$CeCo_{1.67}Rh_{0.33}$	0.47	C15
$Ce_xGd_{1-x}Ru_2$	3.2–5.2	C15
$CeIr_3$	3.34	
$CeIr_5$	1.82	
$Ce_{0.005}La_{0.995}$	4.6	
Ce_xLa_{1-x}	1.3–6.3	
$Ce_xPr_{1-x}Ru_2$	1.4–5.3	C15
Ce_xPt_{1-x}	0.7–1.55	
$CeRu_2$	6.0	C15
$Ce_3Mo_6Se_5$	5.7	hR15 (Mo_6PbS_8)
$Ce_2Mo_6Te_6$	1.7	Same
$Co_xFe_{1-x}Si_2$	1.4 (max.)	C1
$CoHf_2$	0.56	$E9_3$
$CoLa_3$	4.28	
$Co_4La_3Sn_{13}$	2.8	cP40
$CoLu_3$	~0.35	
Co_xLuSn_y	1.5	cP40
$Co_{0–0.01}Mo_{0.8}Re_{0.2}$	2–10	
$Co_{0.02–0.10}Nb_3Rh_{0.98–0.90}$	2.28–1.90	A15
$Co_xNi_{1-x}Si_2$	1.4 (max.)	C1
$Co_{0.5}Rh_{0.5}Si_2$	2.5	
$Co_xRh_{1-x}Si_2$	3.65 (max.)	
$Co_{\sim0.3}So_{\sim0.7}$	~0.35	
$Co_4Sc_5Si_{10}$	5.0	tP38 ($Co_4Sc_5Si_{10}$)
$CoSi_2$	1.40; 1.22	C1
Co_xSn_yYb	2.5	cP40
Co_3Th_7	1.83	$D10_2$
Co_xTi_{1-x}	2.8 (max.)	Co in α-Ti
Co_xTi_{1-x}	3.8 (max.)	Co in β-Ti
$CoTi_2$	3.44	$E9_3$
CoTi	0.71	A2
CoU	1.7	B2, distorted
CoU_6	2.29	$D2_c$
$Co_{0.28}Y_{0.72}$	0.34	
CoY_3	<0.34	
$CoZr_2$	6.3	C16
$Co_{0.1}Zr_{0.9}$	3.9	A3
$Cr_{0.6}Ir_{0.4}$	0.4	H.C.P.
$Cr_{0.65}Ir_{0.35}$	0.59	H.C.P.
$Cr_{0.7}Ir_{0.3}$	0.76	H.C.P.
$Cr_{0.72}Ir_{0.28}$	0.83	
Cr_3Ir	0.45	A15
$Cr_{0–0.1}Nb_{1–0.9}$	4.6–9.2	A2
$Cr_{0.80}Os_{0.20}$	2.5	Cubic
Cr_3Os	4.68	A15-cP8 (Cr_3Si)
Cr_xRe_{1-x}	1.2–5.2	
$Cr_{0.4}Re_{0.6}$	2.15	$D8_b$
$Cr_{0.8–0.6}Rh_{0.2–0.4}$	0.5–1.10	A3
Cr_3Rh	0.3	A15-cP8
Cr_3Ru (annealed)	3.3	A15
Cr_2Ru	2.02	$D8_b$
Cr_3Ru_2	2.10	$D8_b$-tP30 (CrFe)
$Cr_{0.1–0.5}Ru_{0.9–0.5}$	0.34–1.65	A3
Cr_xTi_{1-x}	3.6 (max.)	Cr in α-Ti
Cr_xTi_{1-x}	4.2 (max.)	Cr in β-Ti
$Cr_{0.1}Ti_{0.3}V_{0.6}$	5.6	
$Cr_{0.0175}U_{0.9825}$	0.75	β-phase
$Cs_{0.32}O_3W$	1.12	Hexagonal
$Cu_{0.15}In_{0.85}$ (film)	3.75	
$Cu_{0.04–0.08}In_{0.94–0.92}$	4.4	
CuLa	5.85	
$Cu_2Mo_6O_2S_6$	9	hR15 (Mo_6PbS_8)
$Cu_2Mo_6Se_8$	5.9	Same
Cu_xPb_{1-x}	5.7–7.7	
CuS	1.62	B18
CuS_2	1.48–1.53	C18
CuSSe	1.5–2.0	C18
$CuSe_2$	2.3–2.43	C18
CuSeTe	1.6–2.0	C18
Cu_xSn_{1-x}	3.2–3.7	
Cu_xSn_{1-x} (film, made at 10K)	3.6–7	
Cu_xSn_{1-x} (film, made at 300K)	2.8–3.7	
$CuTe_2$	<1.25–1.3	C18
$CuTh_2$	3.49	C16
$Cu_{0–0.027}V$	3.9–5.3	A2
CuY	0.33	B2-cP2 (CsCl)
Cu_xZn_{1-x}	0.5–0.845	
$DyMo_6S_8$	2.1	hR15
Er_xLa_{1-x}	1.4–6.3	
$ErMo_6S_8$	2.2	hR15
$ErMo_6Se_8$	6.2	hR15
$Fe_3Lu_2Si_5$	6.1	tP40 ($Fe_3Sc_2Si_5$)
$Fe_{0–0.04}Mo_{0.8}Re_{0.2}$	1–10	
$Fe_{0.05}Ni_{0.05}Zr_{0.90}$	~3.9	

Substance	T_c, K	Crystal structure type
Fe_3Re_2	6.55	$D8_b$-tP30 (FeCr)
$Fe_3Sc_2Si_5$	4.52	tP40
Fe_3Si_5Tm	1.3	Same
$Fe_3Si_5Y_2$	2.4	Same
Fe_3Th_7	1.86	D10
Fe_xTi_{1-x}	3.2 (max.)	Fe in α-Ti
Fe_xTi_{1-x}	3.7 (max.)	Fe in β-Ti
$Fe_xTi_{0.6}V_{1-x}$	6.8 (max.)	
FeU_6	3.86	$D2_c$
$Fe_{0.1}Zr_{0.9}$	1.0	A3
$Ga_{0.5}Ge_{0.5}Nb_3$	7.3	A15
Ga_2Ge_2U	0.87	B2-cP2
$GaHf_2$	0.21	C16-tI12 (Al_2Cu)
$GaLa_3$	5.84	
Ga_3Lu	2.3	B2-cP2
Ga_2Mo	9.5	
$GaMo_3$	0.76	A15
GaN (black)	5.85	B4
$Ga_{0.7}Pt_{0.3}$	2.9	C1
GaPt	1.74	B20
GaSb (120kbar, 77K, annealed)	4.24	A5
GaSb (unannealed)	~5.9	
$Ga_{0-1}Sn_{1-0}$ (quenched)	3.47–4.18	
$Ga_{0-1}Sn_{1-0}$ (annealed)	2.6–3.85	
GaTe	0.17	mC24 (GaTe)
Ga_5V_2	3.55	Tetragonal (Mn_2Hg_5)
$GaV_{4.5}$	9.15	
Ga_3Zr	1.38	
Ga_3Zr_5	3.8	$D8_8$-hP16 (Mn_5Si_3)
Gd_xLa_{1-x}	< 1.0–5.5	
$GdMo_6S_8$	3.5	hR15
$GdMo_6Se_8$	5.6	hR15
$Gd_xOs_2Y_{1-x}$	1.4–4.7	
$Gd_xRu_2Th_{1-x}$	3.6 (max.)	C15
$Ge_{10}As_4Y_5$	9.06	tP38 ($C0_4Sc_5Si_{10}$)
GeIr	4.7	B31
GeIrLa	1.64	tI12 (LaPtSi)
$Ge_{10}Ir_4Lu_5$	2.60	tP38
$Ge_{10}Ir_4Y_5$	2.62	tP38
Ge_2La	1.49; 2.2	Orthorhombic, distorted (Mn_2Hg_5)
GeLaPt	3.53	tI12
$Ge_{13}Lu_3Os_4$	3.6	cP40 ($Pr_3Rh_2Sn_{13}$)
$Ge_{10}Lu_5Rh_4$	2.79	tP38
$Ge_{13}Lu_3Ru_4$	2.3	cP40
$GeMo_3$	1.43	A15
$GeNb_2$	1.9	
$Ge_{0.29}Nb_{0.71}$	6	A15
GePt	0.40	B31
Ge_3Rh_5	2.12	Orthorhombic, related to $InNi_2$
GeRh	0.96	B31-oP8 (MnP)
$Ge_{13}Rh_4Sc_3$	1.9	c P40
$Ge_{10}Rh_4Y_5$	1.35	tP38
$Ge_{13}Ru_4Y_3$	1.7	cP40
Ge_2So	1.3	
$GeTa_3$	8.0	A15-cP8 (Cr_3Si)
Ge_3Te_4 ($n = 1.06 \times 10^{22}$)	1.55–1.80	Rhombohedral
Ge_xTe_{1-x} ($n = 8.5–64 \times 10^{20}$)	0.07–0.41	R1
GeV_3	6.01	A15
Ge_2Y	3.80	C_c
$Ge_{1.62}Y$	2.4	
Ge_2Zr	0.30	oC12 ($ZrSi_2$)
$GeZr_3$	0.4	$L1_2$-tP32 (Ti_3P)
$H_{0.33}Nb_{0.67}$	7.28	B.C.C.
$H_{0.1}Nb_{0.9}$	7.38	Same
$H_{0.05}Nb_{0.95}$	7.83	Same
$H_{0.12}Ta_{0.88}$	2.81	B.C.C.
$H_{0.08}Ta_{0.92}$	3.26	Same
$H_{0.04}Ta_{0.96}$	3.62	Same
HfIrSi	3.50	C37-cP12 (Co_2Si)
$HfMo_2$	0.05	hP24 (Ni_2Mn)
$HfN_{0.989}$	6.6	B1
$Hf_{0-0.5}Nb_{1-0.5}$	8.3–9.5	A2
$Hf_{0.75}Nb_{0.25}$	> 4.2	
$HfOs_2$	2.69	C14
HfOsP	6.1	C22-hP9 (Fe_2P)
HfPRu	9.9	Same
$HfRe_2$	4.80	C14
$Hf_{0.14}Re_{0.86}$	5.86	A12
$Hf_{0.99-0.96}Rh_{0.01-0.04}$	0.85–1.51	
$Hf_{0-0.55}Ta_{1-0.45}$	4.4–6.5	A2
HfV_2	8.9–9.6	C15
Hg_xIn_{1-x}	3.14–4.55	
HgIn	3.81	
Hg_2K	1.20	Orthorhombic
Hg_3K	3.18	
Hg_4K	3.27	
Hg_8K	3.42	
Hg_3Li	1.7	Hexagonal
$HgMg_3$	0.17	hP8 (Na_3As)
Hg_2Mg	4.0	tI6 ($MoSi_2$)
Hg_3Mg_5	0.48	$D8_8$-hP16 (Mn_5Si_3)
Hg_2Na	1.62	Hexagonal
Hg_4Na	3.05	
Hg_xPb_{1-x}	4.14–7.26	
HgSn	4.2	
Hg_xTl_{1-x}	2.30–4.19	
Hg_5Tl_2	3.86	
Ho_xLa_{1-x}	1.3–6.3	
$Ho_{1.2}Mo_6Se_8$	6.1	$D10_2$-hR12 (Be_3Nb)
$In_{1-0.86}Mg_{0-0.14}$	3.395–3.363	
$In_2Mo_6Te_6$	2.6	hR15 (Mo_6PbS_8)
$InNb_3$ (high pressure and temp.)	4–8; 9.2	A15
$In_{0.5}Nb_3Zr_{0.5}$	6.4	
$In_{0.11}O_3W$	< 1.25–2.8	Hexagonal
$In_{0.95-0.85}Pb_{0.05-0.15}$	3.6–5.05	
$In_{0.98-0.91}Pb_{0.02-0.09}$	3.45–4.2	
InPb	6.65	
InPd	0.7	B2
InSb (quenched from 170 kbar into liquid N_2)	4.8	Like A5
InSb	2.1	B4
$(InSb)_{0.95-0.10}Sn_{0.05-0.90}$ (various heat treatments)	3.8–5.1	
$(InSb)_{0-0.07}Sn_{1-0.93}$	3.67–3.74	
In_3Sn	~5.5	
In_xSn_{1-x}	3.4–7.3	

Substance	T_c, K	Crystal structure type
$In_{0.82–1}Te$ (n = 0.83–1.71 × 10^{22})	1.02–3.45	B1
$In_{1.000}Te_{1.002}$	3.5–3.7	B1
In_3Te_4 (n = 4.7 × 10^{21})	1.15–1.25	Rhombohedral
In_xTl_{1-x}	2.7–3.374	
$In_{0.8}Tl_{0.2}$	3.223	
$In_{0.62}Tl_{0.38}$	2.760	
$In_{0.78–0.69}Tl_{0.22–0.31}$	3.18–3.32	Tetragonal
$In_{0.69–0.62}Tl_{0.31–0.38}$	2.98–3.3	F.C.C.
Ir_2La	0.48	C15
Ir_3La	2.32	$D10_2$
Ir_3La_7	2.24	$D10_2$
Ir_5La	2.13	
$IrLaSi_2$	2.03	oC16 ($CeNiSi_2$)
$IrLaSi_3$	2.7	tI10 ($BaNiSn_3$)
Ir_2Lu	2.47	C15
Ir_3Lu	2.89	C15
$Ir_4Lu_5Si_{10}$	3.9	tP38 ($Co_4Sc_5Si_{10}$)
IrMo	< 1.0	A3
$IrMo_3$	9.6	A15
$IrMo_3$	6.8	$D8_b$
$IrNb_3$	1.9	A15
$Ir_{0.4}Nb_{0.6}$	9.8	$D8_b$
$Ir_{0.37}Nb_{0.63}$	2.32	$D8_b$
IrNb	7.9	$D8_b$
$Ir_{1.15}Nb_{0.85}$	4.6	oP12 (IrTa)
$Ir_{0.02}Nb_3Rh_{0.98}$	2.43	A15
$Ir_{0.05}Nb_3Rh_{0.95}$	2.38	A15
$Ir_{0.287}O_{0.14}Ti_{0.573}$	5.5	$E9_3$
$Ir_{0.265}O_{0.035}Ti_{0.65}$	2.30	$E9_3$
Ir_xOs_{1-x}	0.3–0.98	
$Ir_{1.5}Os_{0.5}$	2.4	C14
IrOsY	2.6	C15
IrSiY	2.70	C37-oP12 (Co_2Si)
IrSiZr	2.04	Same
Ir_2Sc	2.07	C15
$Ir_{2.5}Sc$	2.46	C15
$Ir_4Sc_5Si_{10}$	8.46	tP38
Ir_2Si_2Th	2.14	tI10
$IrSi_3Th$	1.75	tI10
IrSiTh	6.50	tI12 (LaPtSi)
Ir_2Si_2Y	2.60	tI10 (Al4Ba)
$Ir_4Si_{10}Y_5$	3.10	tP38
$Ir_3Si_5Y_2$	2.83	oI40
$IrSn_2$	0.65–0.78	C1
Ir_2Sr	5.70	C15
Ir_7Ta_{13}	1.2	$D8_b$-tP30 (FeCr)
$Ir_{0.5}Te_{0.5}$	~3	
$IrTe_3$	1.18	C2
IrTh	< 0.37	B_f
Ir_2Th	6.50	C15
Ir_3Th	4.71	
Ir_3Th_7	1.52	$D10_2$
Ir_5Th	3.93	$D2_d$
$IrTi_3$	5.40	A15
IrV_2	1.39	A15
IrW_3	3.82	
$Ir_{0.28}W_{0.72}$	4.49	
Ir_2Y	2.18; 1.38	C15
$Ir_{0.69}Y_{0.31}$	1.98; 1.44	C15
$Ir_{0.70}Y_{0.30}$	2.16	C15
Ir_2Y_3	1.61	
Ir_3Y	3.50	$D10_2$-hR13 (Be_3Nb)
Ir_xY_{1-x}	0.3–3.7	
Ir_2Zr	4.10	C15
$Ir_{0.1}Zr_{0.9}$	5.5	A3
$K_2Mo_{15}S_{19}$	3.32	hR15
$K_{0.27–0.31}O_3W$	0.50	Hexagonal
$K_{0.40–0.57}O_3W$	1.5	Tetragonal
$La_{0.55}Lu_{0.45}$	2.2	Hexagonal, La type
$La_{0.8}Lu_{0.2}$	3.4	Same
$LaMg_2$	1.05	C15
$LaMo_6S_8$	7.1	hR15
LaN	1.35	
$LaOs_2$	6.5	C15
$LaPt_2$	0.46	C15
$La_{0.28}Pt_{0.72}$	0.54	C15
LaPtSi	3.48	tI12
$LaRh_3$	2.60	
$LaRh_5$	1.62	
La_7Rh_3	2.58	$D10_2$
$LaRhSi_2$	3.42	oC16 ($CeNiSi_2$)
$La_2Rh_3Si_5$	4.45	oI40 ($Co_3Si_5U_2$)
$LaRhSi_3$	2.7	tl10 ($BaNiSn_3$)
$LaRh_2Si_2$	3.90	tl10 (Al_4Ba)
$LaRu_2$	1.63	C15
La_3S_4	6.5	$D7_3$
La_3Se_4	8.6	$D7_3$
$LaSi_2$	2.3	C_c
La_xY_{1-x}	1.7–5.4	
LaZn	1.04	B2
$Li_2Mo_6S_8$	4.2	hR15
LiPb	7.2	
$LuOs_2$	3.49	C14
$Lu_{0.275}Rh_{0.725}$	1.27	C15
$LuRh_5$	0.49	
$Lu_5Rh_4Si_{10}$	3.95	tP38 ($Co_4So_5Si_{10}$)
$LuRu_2$	0.86	C14
$Mg_{1.14}Mo_{6.6}S_8$	3.5	hR15
Mg2Nb	5.6	
$Mg_{\sim 0.47}Tl_{\sim 0.53}$	2.75	B2
MgZn	0.9	A3-oP4 (AuCd)
Mn_xTi_{1-x}	2.3 (max.)	Mn in -Ti
Mn_xTi_{1-x}	1.1–3.0	Mn in -Ti
MnU_6	2.32	$D2_c$
Mo_2N	5.0	F.C.C.
$Mo_6Na_2S_8$	8.6	hR15
Mo_xNb_{1-x}	0.016–9.2	
$Mo_{5.25}Nb_{0.75}Se_8$	6.2	hR15
Mo_6NdSa_8	8.2	hR15
Mo_3Os	7.2	A15
$Mo_{0.62}Cs_{0.38}$	5.65	$D8_b$
Mo_3P	5.31	DO_e
$Mo_6Pb_{1.2}Se_8$	6.75	hR15
$Mo_{0.5}Pd_{0.5}$	3.52	A3
Mo_6PrSe_8	9.2	hR15
MoRe	7.8	$D8_b$-tP30
$MoRe_3$	9.25; 9.89	A12
Mo_xRe_{1-x}	1.2–12.2	
$Mo_{0.42}Re_{0.58}$	6.35	$D8_b$
MoRh	1.97	A3
Mo_xRh_{1-x}	1.5–8.2	B.C.C.

Substance	T_c, K	Crystal structure type
MoRu	9.5–10.5	A3
$Mo_{0.61}Ru_{0.39}$	7.18	$D8_b$
$Mo_{0.2}Ru_{0.8}$	1.66	A3
Mo_3Ru_2	7.0	$D8_b$-tP30
$Mo_4Ru_2Te_8$	1.7	hR15
Mo_6S_8	1.85	hR15
Mo_6S_8Sc	3.6	hR15
$Mo_6S_8Sm_{1.2}$	2.9	hR15
Mo_6S_8Tb	2.0	hR15
Mo_6S_8Tl	8.7	hR15
$Mo_6S_8Tm_{1.2}$	2.1	hR15
$Mo_6S_8Y_{1.2}$	3.0	hR15
Mo_6S_8Yb	9.2	hR15
$Mo_{6.6}S_8Zn_{11}$	3.6	hR15
Mo_3Sb_4	2.1	
Mo_6Se_8	6.3	hR15
$Mo_6Se_8Sm_{1.2}$	6.8	hR15
$Mo_6Se_8Sn_{1.2}$	6.8	hR15
Mo_6Se_8Tb	5.7	hR15
Mo_3Se_3Tl	4.0	hP14
$Mo_6Se_8Tm_{1.2}$	6.3	hR15
Mo_6Se_8Yb	6.2	hR15
Mo_3Si	1.30	A15
$MoSi_{0.7}$	1.34	
Mo_xSiV_{3-x}	4.54–16.0	A15
$Mo_{5.25}Ta_{0.75}Te_8$	1.7	hR15
Mo_6Te_8	1.7	hR15
$Mo_{0.16}Ti_{0.84}$	4.18; 4.25	
$Mo_{0.913}Ti_{0.087}$	2.95	
$Mo_{0.04}Ti_{0.96}$	2.0	Cubic
$Mo_{0.025}Ti_{0.975}$	1.8	
Mo_xU_{1-x}	0.7–2.1	
Mo_xV_{1-x}	0–~5.3	
Mo_2Zr	4.25–4.75	C15
NNb (film)	6–9	B1
$N_xO_yTi_z$	2.9–5.6	Cubic
$N_xO_yV_z$	5.8–8.2	Cubic
$N_{0.34}Re$	4–5	F.C.C.
NTa (film)	4.84	B1
$N_{0.6-0.987}Ti$	< 1.17–5.8	B1
$N_{0.82-0.99}V$	2.9–7.9	B1
NZr	9.8	B1
$N_{0.906-0.984}Zr$	3.0–9.5	B1
$Na_{0.28-0.35}O_3W$	0.56	Tetragonal
$Na_{0.28}Pb_{0.72}$	7.2	
NbO	1.25	
$NbOs_2$	2.52	A12
Nb_3Os	1.05	A15
$Nb_{0.6}Os_{0.4}$	1.89; 1.78	$D8_b$
$Nb_3Os_{0.02-0.10}Rh_{0.98-0.90}$	2.42–2.30	A15
Nb_3P	1.8	$L1_2$tP32 (Ti_3P)
NbPRh	4.08	C37-oP12 (Co_2Si)
$Nb_{0.6}Pd_{0.4}$	1.60	$D8_f$ plus cubic
$Nb_3Pd_{0.02-0.10}Rh_{0.92-0.90}$	2.49–2.55	A15
$Nb_{0.62}Pt_{0.38}$	4.21	$D8_b$
Nb_5Pt_3	3.73	$D8_b$
$Nb_3Pt_{0.02-0.98}Rh_{0.98-0.02}$	2.52–9.6	A15
$NbRe_3$	5.27	$D8_b$-tP30 (FeCr)
$Nb_{0.38-0.18}Re_{0.62-0.82}$	2.43–9.70	A15
NbRe	3.8	$D8_b$-tP30
NbReSi	5.1	oI36 (FeTiSi)
Nb_3Rh	2.64	A15
$Nb_{0.6}Rh_{0.40}$	4.21	$D8_b$ plus other
$Nb_{0.9}Rh_{1.1}$	3.07	A3-oP4 (AuCd)
$Nb_3Rh_{0.98-0.90}Ru_{0.02-0.10}$	2.42–2.44	A15
Nb_xRu_{1-x}	1.2–4.8	
NbRuSi	2.65	oI36
NbS_2	6.1–6.3	Hexagonal, $NbSe_2$ type
NbS_2	5.0–5.5	Hexagonal, three-layer type
Nb_3Sb	0.2	$L1_2$-tP32 (Ti_3P)
$Nb_3Sb_{0-0.7}Sn_{1-0.3}$	6.8–18	A15
$NbSe_2$	5.15–5.62	Hexagonal
$Nb_{1-1.05}Se_2$	2.2–7.0	Same
Nb_3Se_4	2.0	hP14
Nb_3Si	1.5	$L1_2$
Nb_3SiSnV_3	4.0	
$NbSn_2$	2.60	Orthorhombic
Nb_6Sn_5	2.8	oI44 (Sn_5Ti_6)
NbSnTaV	6.2	A15
$NbSnV_2$	5.5	A15
Nb_2SnV	9.8	A15
Nb_xTa_{1-x}	4.4–9.2	A2
Nb_3Te_4	1.8	hP14
Nb_xTi_{1-x}	0.6–9.8	
$Nb_{0.6}Ti_{0.4}$	9.8	
Nb_xU_{1-x}	1.95 (max.)	
$Nb_{0.88}V_{0.12}$	5.7	A2
$Nb_{0.5}V_{1.5}Zr$	4.3	C15-hP12 ($MgZn_2$)
$Ni_{0.3}Th_{0.7}$	1.98	$D10_2$
$NiZr_2$	1.52	
$Ni_{0.1}Zr_{0.9}$	1.5	A3
$O_3Rb_{0.27-0.29}W$	1.98	Hexagonal
OSn	3.81	tP4 (PbO)
O_3SrTi (n = 1.7–12.0 × 10^{19})	0.12–0.37	
O_3SrTi (n = 10^{18}–10^{21})	0.05–0.47	
O_3SrTi (n = 10^{20})	0.47	
$O_3Sr_{0.08}W$	2–4	Hexagonal
OTi	0.58	
$O_3Tl_{0.30}W$	2.0–2.14	Hexagonal
OV_3Zr_3	7.5	$E9_3$
OW_3 (film)	3.35; 1.1	A15
OsPti	1.2	C22-hP9 (Fe_2P)
OsPZr	7.4	Same
OsReY	2.0	C14
Os_2Sc	4.6	C14
OsTa	1.95	A12
Os_3Th_7	1.51	$D10_2$
Os_xW_{1-x}	0.9–4.1	
OsW_3	~3	
Os_2Y	4.7	C14
Os_2Zr	3.0	C14
Os_xZr_{1-x}	1.5–5.6	
PPb	7.8	
OsW_2	3.81	$D8_b$-tP30 (FeCr)
$PPd_{3.0-3.2}$	<0.35–0.7	DO_{11}
P_3Pd_7 (high temperature)	1.0	Rhombohedral
P_3Pd_7 (low temperature)	0.70	Complex
PRh	1.22	
PRh_2	1.3	C1
P_4Rh_5	1.22	oP28 ($CaFe_2O_4$)
PRhTa	4.41	C37-oP12 (Co_2Si)

Substance	T_c, K	Crystal structure type
PRhZr	1.55	Same
PRuTi	1.3	C22-hP9 (Fe_2P)
PRuZr	3.46	C37-oP12
PW_3	2.26	DO_e
Pb_2Pd	2.95	C16
Pb_4Pt	2.80	Related to C16
Pb_2Rh	2.66	C16
PbSb	6.6	
PbTe (plus 0.1 w/o Pb)	5.19	
PbTe (plus 0.1 w/o Te)	5.24–5.27	
$PbTl_{0.27}$	6.43	
$PbTl_{0.17}$	6.73	
$PbTl_{0.12}$	6.88	
$PbTl_{0.075}$	6.98	
$PbTl_{0.04}$	7.06	
$Pb_{1-0.26}Tl_{0-0.74}$	7.20–3.68	
$PbTl_2$	3.75–4.1	
Pb_3Zr_5	4.60	$D8_8$
$PbZr_3$	0.76	A15
$Pd_{0.9}Pt_{0.1}Te_2$	1.65	C6
$Pd_{0.05}Ru_{0.05}Zr_{0.9}$	~9	
$Pd_{2.2}S$ (quenched)	1.63	Cubic
$PdSb_2$	1.25	C2
PdSb	1.5	$B8_1$
PdSbSe	1.0	C2
PdSbTe	1.2	C2
Pd_4Se	0.42	Tetragonal
$Pd_{6-7}Se$	0.66	Like Pd_4Te
$Pd_{2.8}Se$	2.3	
Pd_xSe_{1-x}	2.5 (max.)	
PdSi	0.93	B31
PdSn	0.41	B31
$PdSn_2$	3.34	
Pd_2Sn	0.41	C37
Pd_3Sn	0.47–0.64	$B8_2$
Pd_2SnTm	1.77	DO_3-cF16 (BiF_3)
Pd_2SnY	4.92	Same
Pd_2SnYb	1.79	Same
PdTe	2.3; 3.85	$B8_1$
$PdTe_{1.02-1.08}$	2.56–1.88	$B8_1$
$PdTe_2$	1.69	C6
$PdTe_{2.1}$	1.89	C6
$PdTe_{2.3}$	1.85	C6
$Pd_{1.1}Te$	4.07	$B8_1$
Pd_3Te	0.76	cI2 (W)
$PdTh_2$	0.85	C16
$Pd_{0.1}Zr_{0.9}$	7.5	A3
PtSb	2.1	$B8_1$
PtSi	0.88	B31
PtSn	0.37	$B8_1$
$PtSn_4$	2.38	C16-oC20 ($PdSn_4$)
Pt_3Ta_7	1.5	$D8_b$-tP30
$PtTa_3$	0.4	A15-cP8 (Cr_3Si)
PtTe	0.59	Orthorhombic
PtTh	0.44	B_f
Pt_3Th_7	0.98	$D10_2$
Pt_5Th	3.13	
$PtTi_3$	0.58	A15
$Pt_{0.02}U_{0.98}$	0.87	β-phase
$PtV_{2.5}$	1.36	A15
PtV_3	2.87–3.20	A15
$PtV_{3.5}$	1.26	A15
$Pt_{0.5}W_{0.5}$	1.45	A1
Pt_xW_{1-x}	0.4–2.7	
Pt_2Y_3	0.90	
Pt_2Y	1.57; 1.70	C15
Pt_3Y_7	0.82	$D10_2$
PtZr	3.0	A3
Re_2Sc	4.2	C15-hP12 ($MgZn_2$)
$Re_{24}Sc_5$	2.2	A12-cI58 (Mg)
ReSiTa	4.4	oI36 (FeTiSi)
$Re_3Si_5Y_2$	1.76	tP40 ($Fe_3Sc_2Si_5$)
Re_3Ta_2	1.4	$D8_b$-tP30 (FeCr)
$Re_{0.64}Ta_{0.36}$	1.46	A12
Re_3Ta	6.78	A12-cI58 (Mn)
$Re_{24}Ti_5$	6.60	A12
Re_xTi_{1-x}	6.6 (max.)	
$Re_{0.76}V_{0.24}$	4.52	$D8_b$
Re_3V	6.26	$D8_b$-tP30
$Re_{0.92}V_{0.08}$	6.8	A3
$Re_{0.6}W_{0.4}$	6.0	
$Re_{0.5}W_{0.5}$	5.12	$D8_b$
$Re_{13}W_{12}$	5.2	$D8_b$-tP30
Re_3W	9.0	A12-cI58
Re_2Y	1.83	C14
Re_2Zr	5.9	C14
Re_3Zr	7.40	A12-cI58
Re_6Zr	7.40	Same
$Rh_{17}S_{15}$	5.8	Cubic
$Rh_{\sim0.24}Sc_{\sim0.76}$	0.88; 0.92	
$Rh_4Sc_5Si_{10}$	8.54	tP38
$Rh_4Sc_3Sn_{13}$	4.5	cP40
Rh_xSe_{1-x}	6.0 (max.)	
$RhSi_3Th$	1.76	tI10
$Rh_{0.86}Sc_{1.04}Th$	6.45	tI12
Rh_2Si_2Y	3.11	tI10
$Rh_3Si_5Y_2$	2.70	oI40
$Rh_4Sn_{13}Sr_3$	4.3	cP40
Rh_xSn_yTh	1.9	cI2 (W)
Rh_xSn_yTm	2.3	cP40
$Rh_4Sn_{13}Y_3$	3.2	cP40
Rh_2Sr	6.2	C15
$Rh_{0.4}Ta_{0.6}$	2.35	$D8_b$
$RhTe_2$	1.51	C2
$Rh_{0.67}Te_{0.33}$	0.49	
Rh_xTe_{1-x}	1.51 (max.)	
RhTh	0.36	B_f
Rh_3Th_7	2.15	$D10_2$
Rh_5Th	1.07	
Rh_xTi_{1-x}	2.25–3.95	
$Rh_{0.02}U_{0.98}$	0.96	
RhV_3	0.38	A15
RhW	~3.4	A3
RhY_3	0.65	
Rh_2Y_3	1.48	
Rh_3Y	1.07	C15
Rh_5Y	0.56	
Rh_3Y_7	0.32	hP20 (Fe_3Th_7)
$Rh_{0.005}Zr$ (annealed)	5.8	
$Rh_{0-0.45}Zr_{1-0.55}$	2.1–10.8	
$Rh_{0.1}Zr_{0.9}$	9.0	H.C.P.
Ru_2Sc	1.67	C14
RuSiTa	3.15	oI36

Substance	T_c, K	Crystal structure type
Ru_3Si_2Th	3.98	hP12
Ru_3Si_2Y	3.51	hP12
$Ru_{1.1}Sn_{3.1}Y$	1.3	cP40
Ru_2Th	3.56	C15
RuTi	1.07	B2
$Ru_{0.05}Ti_{0.95}$	2.5	
$Ru_{0.1}Ti_{0.9}$	3.5	
$Ru_xTi_{0.6}V_y$	6.6 (max.)	
Ru_3U	0.15	$L1_2$-cP4
$Ru_{0.45}V_{0.55}$	4.0	B2
RuW	7.5	A3
Ru_2Y	1.52	C14
Ru_2Zr	1.84	C14
$Ru_{0.1}Zr_{0.9}$	5.7	A3
STh	0.5	B1-cF8 (NaCl)
SbSn	1.30–1.42	B1 or distorted
$SbTa_3$	0.72	A15-cP8 (Cr_3Si)
$SbTi_3$	5.8	Same
Sb_2Ti_7	5.2	
$Sb_{0.01-0.03}V_{0.99-0.97}$	3.76–2.63	A2
SbV_3	0.80	A15
SeTh	1.7	B1-cF8
$SiMo_3$	1.4	A15-cP8
Si_2Th	3.2	C_c, α-phase
Si_2Th	2.4	C32, β-phase
$SiV_{2.7}Ru_{0.3}$	2.9	A15
Si_2W_3	2.8; 2.84	
$SiZr_3$	0.5	$L1_2$-tP32 (Ti_3P)
$Sn_{0.174-0.104}Ta_{0.826-0.896}$	6.5–< 4.2	A15
$SnTa_3$	8.35	A15, highly ordered
$SnTa_3$	6.2	A15, partially ordered
$SnTaV_2$	2.8	A15
$SnTa_2V$	3.7	A15
Sn_xTe_{1-x} ($n = 10.5–20 \times 10^{20}$)	0.07–0.22	B1
Sn_3Th	3.33	$L1_2$-cP4
$SnTi_3$	5.80	A15-cP8
Sn_xTl_{1-x}	2.37–5.2	
SnV_3	3.8	A15
$Sn_{0.02-0.057}V_{0.98-0.943}$	2.87–~1.6	A2
$SnZr_3$	0.92	A15-cP8
$Ta_{0.025}Ti_{0.975}$	1.3	Hexagonal
$Ta_{0.05}Ti_{0.95}$	2.9	Hexagonal
$Ta_{0.05-0.75}V_{0.95-0.25}$	4.30–2.65	A2
$Ta_{0.8-1}W_{0.2-0}$	1.2–4.4	A2
$Tc_{0.1-0.4}W_{0.9-0.6}$	1.25–7.18	Cubic
$Tc_{0.50}W_{0.50}$	7.52	α plus
$Tc_{0.60}W_{0.40}$	7.88	plus α
Tc_6Zr	9.7	A12
TeY	1.02	B1-cF8
$ThTl_3$	0.87	$L1_2$-cP4
$Th_{0-0.55}Y_{1-0.45}$	1.2–1.8	
$Ti_{0.70}V_{0.30}$	6.14	Cubic
Ti_xV_{1-x}	0.2–7.5	
$Ti_{0.5}Zr_{0.5}$ (annealed)	1.23	
$Ti_{0.5}Zr_{0.5}$ (quenched)	2.0	
Tl_3Y	1.52	$L1_2$-cP4
V_2Zr	8.80	C15
$V_{0.26}Zr_{0.74}$	5.9	
W_2Zr	2.16	C15
YZn	0.33	B2-cP2 (CsCl)

* n denotes current carriers concentration in cm^{-3}.

B. Superconductors with T_c > 10K

Substance	T_c,K	Crystal structure type	
Al_2CMo_3	10.0	A13	
$Al_{0.5}Ge_{0.5}Nb$	12.6	A15	
$Al_{\sim 0.8}Ge_{\sim 0.2}Nb_3$	20.7	A15	
$AlNb_3$	18.0	A15	(Cr_3Si)
$AlNb_3$	12.0		(FeCr)
$A1_xNb_{1-x}$	<4.2–13.5	$D8_b$	
$A1_xNb_{1-x}$	12–17.5	A15	
$A1_{0.27}Nb_{0.73-0.48}V_{0-0.25}$	14.5–17.5	A15	
A1 Nb_xV_{1-x}	4.4–13.5		
$A1_{0.1}Si_{0.9}V_3$	14.05		
$A1V_3$	11.8	A15	(Cr_3Si)
$AuNb_3$	11.5	A15	
$Au_{0-0.3}Nb_{1-0.7}$	1.1–11.0		
$Au_{0.02-0.98}Nb_3Rh_{0.98-0.02}$	2.53–10.9	A15	
$AuNb_{3(1-x)}V_{3x}$	1.5–11.0	A15	
$B_{0.03}C_{0.51}Mo_{0.47}$	12.5		
B_4LuRh_4	11.7		(B_4CeCo_4)
B_2LuRu	10		
B_4Rh_4Y	11.3		(B_4CeCo_4)
$B_{0.1}Si_{0.9}V_3$	15.8	A15	
$BaBi_{0.2}O_3Pb_{0.8}$	13.2		
$Ba_2CaCu_2O_8T1_2$	120		
$Ba_2Cu_3LaO_6$	80		
$Ba_2Cu_3O_7Tm$	101		
$Ba_2Cu_3O_7Y$	90		
$(Ba,La)_2CuO_4$	36	A15	(K_2NiF_4)
$Bi_2CaCu_2O_8Sr_2$	110		
$Br_2Mo_6S_6$	13.8		(Mo_6PbS_8)
C_3La	11.0		(C_3Pu_2)
CMo	14.3	B1	(NaC1)
CMo_2	12.2		o**
$C_{0.5}Mo_xNb_{1-x}$	10.8–12.5	B1	
CMo_xTi_{1-x}	10.2(max)	B1	
$CMo_{0.83}Ti_{0.17}$	10.2	B1	
$C_{0-0.38}N_{1-0.62}Ta$	10.0–11.3		
CNb (whiskers)	7.5–10.5		
CNb	11.5	B1	
$C_{0.7-1.0}Nb_{0.3-0}$	6–11	B1	
CNb_xTa_{1-x}	8.2–13.9		
$CNb_{0.6-0.9}W_{0.4-0.1}$	12.5–11.6	B1	
$C_{0.1}Si_{0.9}V_3$	16.4	A15	
CTa	10.3	B1	
$CTa_{1-0.4}W_{0-0.6}$	8.5–10.5	B1	
$C_{0.66}Th_{0.13}Y_{0.21}$	17		(C_3Pu_2)
C_3Y_2	11.5		(C_3Pu_2)
CW	10	B1	
$(Ca,La)_2CuO_4$	18		(K_2NiF_4)
$Cu(La,Sr)_2O_4$	39		
$Cu_{1.8}Mo_6S_8$	10.8		(Mo_6PbS_8)
$Cr_{0.3}SiV_{2.7}$	11.3	A15	
$GaNb_3$	14.5	A15	(Cr_3Si)
$Ga_xNb_3Sn_{1-x}$	14–18.37	A15	
GaV_3	16.8	A15	
$GaV_{2.1-3.5}$	6.3–14.45	A15	
$GeNb_3$	23.2	A15	
$GeNb_3$ (quenched)	6–17	A15	
$Ge_xNb_3Sn_{1-x}$	17.6–18.0	A15	
$Ge_{0.5}Nb_3Sn_{0.5}$	11.3		
$Ge_{0.1}Si_{0.9}V_3$	14.0	A15	
GeV_3	11	A15	
$InLa_3$	9.83; 10.4	LI_2	($AuCu_3$)

Substance	T_c,K	Crystal structure type	
$In_{0-0.3}Nb_3Sn_{1-0.7}$	18.0–18.19	A15	
InV_3	13.9	A15	
$Ir_{0.4}Nb_{0.6}$	10		(FeCr)
$LaMo_6Se_8$	11.4		(Mo_6PbS_8)
LiO_4Ti_2	13.7		($A1_2MgO_4$)
MgB_2	39.0±0.5	C32	
MoN	12; 14.8		h*
Mo_3Os	12.7	A15	
$Mo_6Pb_{0.9}S_{7.5}$	15.2		(Mo_6PbS_8)
Mo_3Re	10.0; 15	A15	
Mo_xRe_{1-x}	1.2–12.2		
$Mo_{0.52}Re_{0.48}$	11.1		
$Mo_{0.57}Re_{0.43}$	14.0		
$Mo_{\sim 0.60}Re_{0.395}$	10.6		
MoRu	9.5–10.5	A3	
Mo_3Ru	10.6	A15	
Mo_6Se_8T1	12.2		(Mo_6PbS_8)
$Mo_{0.3}SiV_{2.7}$	11.7	A15	
Mn_3Si	12.5	A15	
Mo_3Tc	15	A15	
$Mo_{0.3}Tc_{0.7}$	12.0	A15	
Mo_xTc_{1-x}	10.8–15.8		
$MoTc_3$	15.8		
NNb (whiskers)	10–14.5		
NNb (diffusion wires)	16.10		
$N_{0.988}Nb$	14.9; 17.3	B1	
$N_{0.824-0.988}Nb$	14.4–15.3	B1	
$N_{0.7-0.795}Nb$	11.3–12.9		
NNb_xO_y	13.5–17.0	B1	
NNb_xO_y	6.0–11		
$N_{100-42w/o}Nb_{0-58w/o}Ti$	15–16.8		
$N_{100-75w/o}Nb_{0-25w/o}Zr$	12.5–16.35		
NNb_xZr_{1-x}	9.8–13.8	B1	
$N_{0.93}Nb_{0.85}Zr_{0.15}$	13.8	B1	
NTa	12–14	B1	
NZr	10.7	B1	
Nb_3Pt	10.9	A15	
$Nb_{0.18}Re_{0.82}$	10		(Mn)
Nb_3Si	19	A15	
$Nb_{0.3}SiV_{2.7}$	12.8	A15	
Nb_3Sn	18.05	A15	
$Nb_{0.8}Sn_{0.2}$	18.18; 18.5	A15	
Nb_xSn_{1-x} (film)	2.6–18.5		o*
Nb_3Sn_2	16.6		t*
$NbSnTa_2$	10.8	A15	
Nb_2SnTa	16.4	A15	
$Nb_{2.5}SnTa_{0.5}$	17.6	A15	
$Nb_{2.75}SnTa_{0.25}$	17.8	A15	
$Nb_{3x}SnTa_{3(1-x)}$	6.0–18.0		
$Nb_2SnTa_{0.5}V_{0.5}$	12.2	A15	
$NbTc_3$	10.5	A12	
$Nb_{0.75}Zr_{0.25}$	10.8		
$Nb_{0.66}Zr_{0.33}$	10.8		
$PbTa_3$	17	A15	
$RhTa_3$	10	A15	
$RhZr_2$	10.8; 11.3	C16	($A1_2Cu$)
$Rh_{0-0.45}Zr_{1-0.55}$	2.1–10.8		
$SiTi_{0.3}V_{2.7}$	10.9	A15	
SiV_3	17.1	A15	
$SiV_{2.7}Zr_{0.3}$	13.2	A15	

TABLE 5. Critical Field Data

Substance	H_o (oersteds)
Ag_2F	2.5
Ag_7NO_{11}	57
Al_2CMo_3	1700
$BaBi_3$	740
Bi_2Pt	10
Bi_3Sr	530
Bi_5Tl_3	>400
CdSn	>266
$CoSi_2$	105
$Cr_{0.1}Ti_{0.3}V_{0.6}$	1360
$In_{1-0.86}Mg_{0-0.14}$	272.4–259.2
InSb	1100
In_xTl_{1-x}	252–284
$In_{0.8}Tl_{0.2}$	252
$Mg_{0.47}Tl_{0.53}$	220
$Mo_{0.16}Ti_{0.84}$	<985
$NbSn_2$	620
$PbTl_{0.27}$	756
$PbTl_{0.17}$	796
$PbTl_{0.12}$	849
$PbTl_{0.075}$	880
$PbTl_{0.04}$	864

TABLE 6. High Critical Magnetic-Field Superconductive Compounds and Alloys

Substance	T_c, K	H_{c1}, kOe	H_{c2}, kOe	H_{c3}, kOe	T_{obs}, K[a]
Al_2CMo_3	9.8–10.2	0.091	156		1.2
$AlNb_3$		0.375			
$Ba_xO_3Sr_{1-x}Ti$	<0.1–0.55	0.0039 max.			
$Bi_{0.5}Cd_{0.1}Pb_{0.27}Sn_{0.13}$			>24		3.06
Bi_xPb_{1-x}	7.35–8.4	0.122 max.	30 max.		4.2
$Bi_{0.56}Pb_{0.44}$	8.8		15		4.2
$Bi_{7.5w/o}Pb_{92.5w/o}$[b]			2.32		
$Bi_{0.099}Pb_{0.901}$		0.29	2.8		
$Bi_{0.02}Pb_{0.98}$		0.46	0.73		
$Bi_{0.53}Pb_{0.32}Sn_{0.16}$			>25		3.06
$Bi_{1-0.93}Sn_{0-0.07}$			0–0.032		3.7
Bi_5Tl_3	6.4		>5.6		3.35
C_8K (excess K)	0.55		0.160 (H⊥c)		0.32
			0.730 (H∣c)		0.32
C_8K	0.39		0.025 (H⊥c)		0.32
			0.250 (H∣c)		0.32
$C_{0.44}Mo_{0.56}$	12.5–13.5	0.087	98.5		1.2
CNb	8–10	0.12	16.9		4.2
$CNb_{0.4}Ta_{0.6}$	10–13.6	0.19	14.1		1.2
CTa	9–11.4	0.22	4.6		1.2
$Ca_xO_3Sr_{1-x}Ti$	<0.1–0.55	0.002–0.004			
$Cd_{0.1}Hg_{0.9}$ (by weight)		0.23	0.34		2.04
$Cd_{0.05}Hg_{0.95}$		0.28	0.31		2.16
$Cr_{0.10}Ti_{0.30}V_{0.60}$	5.6	0.071	84.4		0
GaN	5.85	0.725			4.2
Ga_xNb_{1-x}			>28		4.2
GaSb (annealed)	4.24		2.64		3.5
$GaV_{1.95}$	5.3		73[e]		
$GaV_{2.1-3.5}$	6.3–14.45		230–300[d]		0
GaV_3		0.4	350[e]		0
			500[d]		
$GaV_{4.5}$	9.15		121[c]		0
Hf_xNb_y			>52–>102		1.2
Hf_xTa_y			>28–>86		1.2
$Hg_{0.05}Pb_{0.95}$		0.235	2.3		
$Hg_{0.101}Pb_{0.899}$		0.23	4.3		4.2
$Hg_{0.15}Pb_{0.85}$	6.75		>13		2.93
$In_{0.98}Pb_{0.02}$	3.45	0.1		0.12	2.76
$In_{0.96}Pb_{0.04}$	3.68	0.1	0.12	0.25	2.94
$In_{0.94}Pb_{0.06}$	3.90	0.095	0.18	0.35	3.12
$In_{0.913}Pb_{0.087}$	4.2	~10.17	0.55	2.65	
$In_{0.316}Pb_{0.684}$		0.155	3.7		4.2
$In_{0.17}Pb_{0.83}$			2.8	5.5	4.2
$In_{1.000}Te_{1.002}$	3.5–3.7		1.2[c]		0
$In_{0.95}Tl_{0.05}$		0.263	0.263		3.3
$In_{0.90}Tl_{0.10}$		0.257	0.257		3.25
$In_{0.83}Tl_{0.17}$		0.242	0.39		3.21
$In_{0.75}Tl_{0.25}$		0.216	0.50		3.16
LaN	1.35	0.45			0.76
La_3S_4	6.5	≈0.15	>25		1.3
La_3Se_4	8.6	≈0.2	>25		1.25
$Mo_{0.52}Re_{0.48}$	11.1		14–21	22–33	4.2
			18–28	37–43	1.3
$Mo_{0.6}Re_{0.395}$	10.6		14–20	20–37	4.2
			19–26	26–37	1.3
$Mo_{0.5}Ti_{0.5}$			75[c]		0
$Mo_{0.16}Ti_{0.84}$	4.18	0.028	98.7[c]		0
			36–38		3.0
$Mo_{0.913}Ti_{0.087}$	2.95	0.060	15		4.2
$Mo_{0.1-0.3}U_{0.9-0.7}$	1.85–2.06		>25		
$Mo_{0.17}Zr_{0.83}$			30		

Substance	T_c, K	H_{c1}, kOe	H_{c2}, kOe	H_{c3}, kOe	T_{obs}, K[a]
$N_{(12.8\ w/o)}Nb$	15.2		>9.5		13.2
NNb (wires)	16.1		153[c]		0
			132		4.2
			95		8
			53		12
NNb_xO_{1-x}	13.5–17.0		38		
NNb_xZr_{1-x}	9.8–13.8		4- >130		4.2
$N_{0.93}Nb_{0.85}Zr_{0.15}$	13.8		>130		4.2
$Na_{0.086}Pb_{0.914}$		0.19	6.0		
$Na_{0.016}Pb_{0.984}$		0.28	2.05		
Nb	9.15		2.020		1.4
			1.710		4.2
Nb		0.4–1.1	3–5.5		4.2
Nb (unstrained)		1.1–1.8	3.40	6–9.1	4.2
Nb (strained)		1.25–1.92	3.44	6.0–8.7	4.2
Nb (cold-drawn wire)		2.48	4.10	≈10	4.2
Nb (film)			>25		4.2
NbSc			>30		
Nb_3Sn		0.170	221		4.2
			70		14.15
			54		15
			34		16
			17		17
$Nb_{0.1}Ta_{0.9}$		0.084	0.154		4.195
$Nb_{0.2}Ta_{0.8}$			10		4.2
$Nb_{0.65\text{-}0.73}Ta_{0.02\text{-}0.10}Zr_{0.25}$			>70–>90		4.2
Nb_xTi_{1-x}			148 max.		1.2
			120 max.		4.2
$Nb_{0.222}U_{0.778}$		1.98	23		1.2
Nb_xZr_{1-x}			127 max.		1.2
			94 max.		4.2
O_3SrTi	0.43	0.0049[c]	0.504[c]		0
O_3SrTi	0.33	0.00195[c]	0.420[c]		0
$PbSb_{1\ w/o}$(quenched)			>1.5		4.2
$PbSb_{1\ w/o}$(annealed)			>0.7		4.2
$PbSb_{2.8\ w/o}$(quenched)			>2.3		4.2
$PbSb_{2.8\ w/o}$(annealed)			>0.7		4.2
$Pb_{0.871}Sn_{0.129}$		0.45	1.1		
$Pb_{0.965}Sn_{0.035}$		0.53	0.56		
$Pb_{1\text{-}0.26}Tl_{0\text{-}0.74}$	7.20–3.68		2–6.9[c]		0
$PbTl_{0.17}$	6.73		4.5[c]		0
$Re_{0.26}W_{0.74}$			>30		
$Sb_{0.93}Sn_{0.07}$			0.12		3.7
SiV_3	17.0	0.55	156[e]		
Sn_xTe_{1-x}		0.00043–0.00236	0.005–0.0775		0.012–0.079
Ta (99.95%)		0.425	1.850		1.3
		0.325	1.425		2.27
		0.275	1.175		2.66
		0.090	0.375		3.72
$Ta_{0.5}Nb_{0.5}$			3.55		4.2
$Ta_{0.65\text{-}0}Ti_{0.35\text{-}1}$	4.4–7.8		>14–138		1.2
$Ta_{0.5}Ti_{0.5}$			138		1.2
Te	3.3	0.25[c]			0
Tc_xW_{1-x}	5.75–7.88		8–44		4.2
Ti				2.7	4.2
$Ti_{0.75}V_{0.25}$	5.3	0.029[c]	199[c]		0
$Ti_{0.775}V_{0.225}$	4.7	0.024[c]	172[c]		0
$Ti_{0.615}V_{0.385}$	7.07	0.050	34		4.2
$Ti_{0.516}V_{0.484}$	7.20	0.062	28		4.2
$Ti_{0.415}V_{0.585}$	7.49	0.078	25		4.2
$Ti_{0.12}V_{0.88}$			17.3	28.1	4.2
$Ti_{0.09}V_{0.91}$			14.3	16.4	4.2
$Ti_{0.06}V_{0.94}$			8.2	12.7	4.2

Substance	T_c, K	H_{c1}, kOe	H_{c2}, kOe	H_{c3}, kOe	T_{obs}, K[a]
$Ti_{0.03}V_{0.97}$			3.8	6.8	4.2
Ti_xV_{1-x}			108 max.		1.2
V	5.31	0.8	3.4		1.79
		0.75	3.15		2
		0.45	2.2		3
		0.30	1.2		4
$V_{0.26}Zr_{0.74}$	≈5.9	0.238			1.05
		0.227			1.78
		0.185			3.04
		0.165			3.5
W (film)	1.7–4.1		>34		1

[a] Temperature of critical field measurement.
[b] w/o denotes weight percent.
[c] Extrapolated.
[d] Linear extrapolation.
[e] Parabolic extrapolation

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